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Effects of temperature on factors relevant to laser operation near 1.6 μ m wavelength in resonantly (in-band) pumped CaF₂:Er and SrF₂:Er crystals: a comparative study

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Abstract

Single crystals of CaF₂ and SrF₂ containing Er^{3+} ions with concentrations between 0.01 and 0.6 at% respectively, were grown using the temperature gradient technique (TGT). Absorption spectra related to the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ transition of Er^{3+} ions were measured at 5 K to investigate the properties of the crystal field splitting of the ${}^{4}I_{13/2}$ multiplet, and at several temperatures in the region 80 K – 300 K to determine the effect of temperature on the spectral bands. The ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ luminescence spectra were recorded within the same temperature range as for absorption measurement. The analysis of absorption and luminescence spectra provides an in-depth knowledge on the effect of temperature on the factors that govern the efficiency of resonant optical pumping near 1.6 µm and the resulting lasing ability of Er^{3+} ions imbedded in CaF₂ and SrF₂ hosts.

1 Introduction

Laser action near 1.6 μ m in CaF₂:Er³⁺ has been reported for the first time by S.A. Pollack in 1963 [1]. In this study a cylindrical rod of CaF_2 doped with 0.1 mol% of Er^{3+} ions was 2 inches in length and 3/8 inches in cross section. It was pumped with a filtered radiation of a xenon flashlamp that delivered light pulses with an input energy of about 1000 J. The measured quantum efficiency of the ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ laser transition excited by pumping into the 375 nm absorption band was about 2% at room temperature and about 6-7%near 77 K. The observed laser performance was not encouraging and for a long time this system has been discarded as laser active material. In subsequent years a considerable interest was paid to the investigation of the structural and optical properties of rare earth doped BaF₂, CaF₂ and SrF₂ hosts in order to understand the nature of luminescent sites and the activator-activator and activator-host interaction.

R. Lisiecki r.lisiecki@intibs.pl Gathered knowledge combined with observed peculiarities of laser performance of Er^{3+} ions in other fluoride hosts such as LiYF_4 [2], or BaY_2F_8 [3] made it possible to discover a new laser potential of CaF_2 , and SrF_2 hosts heavily doped with Er^{3+} ions.

Indeed, C. Labbe et al. [4] reported laser performance of heavily doped Er³⁺:CaF₂ under various pump wavelengths. The laser emitted at 2.8 µm upon pumping at 970 nm with a threshold absorbed pump power of 23 mW and slope efficiency of 30%. It is worth noticing that the pumping wavelength of 970 nm is advantageous in that the upper laser level ⁴I_{11/2} is populated directly assuring thereby the highest pumping efficiency. The authors also observed the laser operation under pumping at 800 or 1545 nm but with a smaller efficiency. In virtually all hosts the lifetime of initial level for the ${}^{4}I_{11/2} \rightarrow {}^{4}I_{13/2}$ laser transition of Er^{3+} ions is shorter than that of the terminal laser level and the laser emission at 2.8 µm is self-terminated. At high concentration of Er³⁺ ions the ion-ion interaction and nonlinear excitation mechanisms are able to overcome this obstacle, however. T.T. Basiev et al. [5] reported CW laser operation in Er³⁺(5%):CaF₂ and Er³⁺(5%):SrF₂ crystals near 2.75 µm with output power of 0.4 and 2 W respectively, upon transverse pumping with a diode laser at 980 nm. Continuous tuning of laser wavelength between 2720 and 2760 nm was achieved in $Er^{3+}(5\%)$:SrF₂ crystal. The bulk thermal damage thresholds measured for

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Er³⁺(5%):CaF₂ and Er³⁺(5%):SrF₂ crystals were approximately the same and equal to 500 W cm⁻³. These reports have been followed by numerous papers devoted mainly to laser operation near 2.75 μm in Er³⁺:CaF₂ with different concentration of Er³⁺ ions. For instance, J. Sulc et al. [6] reported on Er³⁺:CaF₂ ceramic 2.79 μm tunable laser, Ma et al. [7] investigated the effect of Er³⁺ concentration on laser performance of Er³⁺:CaF₂ crystals, Ma et al. [8] reported on improved CW laser performance from a diodepumped Er,Pr:CaF₂ crystal. Mingqui Fan et al. [9] reported on 2.79 μm CW laser operation with a slope efficiency of 41%. Zhen Zhang et al. and Yunfei Wang et al. achieved efficient ~ 2.8 μm CW lasers in extremely lightly doped Er:CaF₂ crystals with concentration of 0.5 at.% and 0.3 at.% [10, 11].

The experimental data related to laser operation near 2.8 µm in Er³⁺:CaF₂ and Er³⁺:SrF₂ are abundant and the interplay between linear and nonlinear processes governing the ${}^{4}I_{11/2} \leftrightarrow {}^{4}I_{13/2}$ transitions involved is understood. Instead, the knowledge of spectroscopic features relevant to the ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ laser transition of Er³⁺ near 1.6 µm in calcium and strontium fluoride is very poor. A paper by Kumar et al. [12] was devoted to this issue. Some related information is included in papers by Labbe [13] and R. Sveikar et al. [14] devoted essentially to laser operation near 2.8 $\mu m.$ On the other hand the ${}^4I_{13/2} \! \rightarrow {}^4I_{15/2}$ laser operation of Er³⁺ near 1.6 µm under direct pumping into the upper laser level has been observed in other erbium-doped hosts. Ter-Gabrielyan et al. investigated the effect of pump wavelength on laser performance of cryo-cooled Er³⁺:YAG laser [15]. Nemec et al. reported laser performance of tunable resonantly pumped Er:GGAG laser [16]. Ter-Gabrielyan et al.

compared spectroscopic and laser properties of resonantly (in-band) pumped Er:YVO₄ and Er:GdVO₄ crystals [17].

In the present work we explore the effect of temperature on optical spectra of absorption and emission transitions between the ${}^{4}I_{15/2}$ and ${}^{4}I_{13/2}$ multiplets of Er^{3+} ions imbedded in CaF₂ and SrF₂ crystals. The aim of the work is to interpret the thermally induced change of contribution of transitions involved based on in-depth analysis of observed spectra and determine the spectroscopic parameters relevant to resonant optical pumping of the ${}^{4}I_{13/2}$ upper laser level and the ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ laser operation at 300 K and at cryogenic temperatures down to 80 K. To the best of our knowledge, these issues have not been reported before.

2 Experimental

The $Er^{3+}:CaF_2$ and $Er^{3+}:SrF_2$ crystals were grown in Shanghai Institute of Ceramics, Chinese Academy of Sciences using the temperature gradient technique (TGT). The detailed growth process is described in [18]. The purity of the $Er^{3+}:CaF_2$ and $Er^{3+}:SrF_2$ crystals was examined with a powder X-ray diffraction method using a Siemens D5000 diffractometer equipped with a copper radiation tube. The measurements were performed in a 20 angle range of 5–90° with a 0.04° step and a count-time of 4 s/step. The XRD patterns are presented in Fig. 1. The appeared doublet lines are related to the unfiltered K α_1 and K α_2 characteristic Cu X-ray radiation. The selected physicochemical properties of CaF₂ and SrF₂ crystals are listed in Table 1. An Agilent Cary 5000 spectrophotometer was used to record unpolarized absorption spectra as

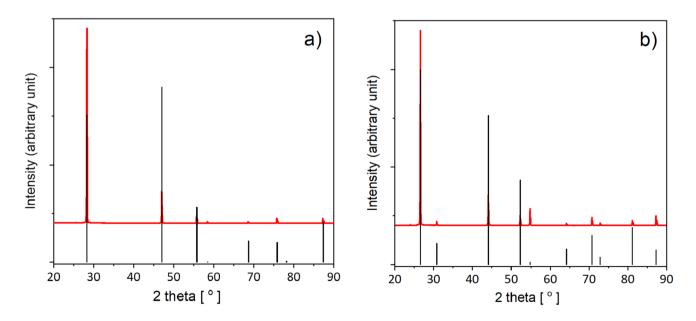


Fig. 1 XRD patterns of a CaF₂ and b SrF₂ crystals (red) and the referenced patterns taken from the ICSD database (black)

Table 1 Selected physicochemical properties of CaF_2 and SrF_2 crystals

| | CaF ₂ | SrF ₂ |
|---|---|---|
| Crystal structure | Fm -3 m (225)-cubic a=5.4629 Å, V=163.03 Å ³ , Z=4 | F m -3 m (225)-cubic a=5.800 Å, V=195.11 Å ³ , Z=4 |
| Density [g/cm ³] | 3.18 | 4.29 |
| Thermal Conductivity [W/m*K] | 9.71 | 8.30 |
| Refractive index | 1.43 | 1.44 |
| First order Raman vibration [cm ⁻¹] | 322 [19] | 285 [20] |
| Energy gap [eV] | 12.10 | 11.25 |

a function of 5 K-300 K temperature. Absorption spectra were measured with an instrumental bandwidth set to 0.05 nm. Near infrared emission spectra were excited by a 975 nm CNI diode laser, dispersed by an Optron DongWoo monochromator with 750 mm focal length and detected by an InGaAs detector. A xenon lamp 380 nm and Hamamatsu R-3896 photomultiplier were used to record the visible luminescence. During temperature-dependent experiments, $Er^{3+}:CaF_2$ and $Er^{3+}:SrF_2$ crystals were mounted in an Oxford Instruments continuous flow liquid helium cryostat equipped with a temperature controller.

3 Results and discussion

Several factors are responsible for the effects of temperature on absorption and emission spectra. First of all, thermal line broadening (1), a mechanism consisting of Raman scattering of phonons by an ion in an excited state (2) and thermal line shift which determines the change of transition energy due to temperature induced displacement of levels (3) involved in the transitions. As result, these factors affect the populations of both the initial and the terminal levels.

In the 4f¹¹ configuration of Er^{3+} ions the lowest energy multiplets are the ⁴I_{15/2} ground state and the ⁴I_{13/2} first excited state. They are separated by about 6500 cm⁻¹. When Er^{3+} ions are incorporated in a crystal host the crystal field splits the ground multiplet and the excited multiplet into a number of crystal field sublevels. In addition, the disparity of size and/or valency between incorporated erbium ions and substituted cations in the crystal structure creates sites differing in the symmetry and strength of the crystal fields. This feature is related to the systems considered in this study.

Figure 2 shows the room temperature absorption spectra of the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ transition for several concentrations of Er^{3+} ions in CaF_{2} and SrF_{2} crystals. The spectra consist of a broad band extending from 1400 to 1650 nm, where several peaks can be identified. Some structures on their tops may be discerned. In these structures the most prominent local peaks are located at 1506, 1517, 1528, 1530 and 1543 nm

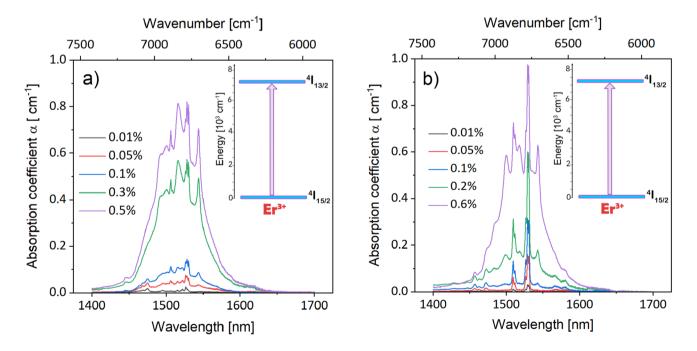


Fig. 2 Room temperature absorption spectra of the ${}^{4}I_{15/2} - {}^{4}I_{13/2}$ transition measured for several concentrations of Er^{3+} ions in a CaF_{2} and b SrF_{2} crystals. Insets show an involved Er^{3+} energy levels scheme

for Er^{3+} in CaF_2 and at 1499, 1510, 1529, 1530 and 1543 nm for Er^{3+} in SrF_2 .

It is worth noticing that the shapes of bands recorded at different concentrations of Er^{3+} in CaF_2 crystal show some differences. The same concerns the spectra for Er^{3+} ions in SrF_2 crystal.

The optimal Er^{3+} concentration in an active medium with a resonantly pumped ${}^{4}\mathrm{I}_{13/2} \rightarrow {}^{4}\mathrm{I}_{15/2}$ laser transition usually stems from a trade-off between endeavor to minimize an adverse self-absorption effect and to maintain sufficient pumping efficiency. It can be seen in Fig. 2 that the peak value of absorption coefficient for a CaF₂ crystal containing 0.5at% Er^{3+} (1.22×10²⁰ ion/cm³) and a SrF₂ crystal containing 0.6at% Er^{3+} (1.23×10²⁰ ion/cm³) equals to 0.82 cm⁻¹ and 0.98 cm⁻¹ respectively.

From the spectra presented in Fig. 2, it follows for example that an end-pumped 1 cm in length cylindrical rod will absorb 56% (Er:CaF₂) and 62% (Er:SrF₂) of the incident light (1528 nm) power, respectively. Therefore, in the rest of this paper, we will limit our discussion to the 0.5at% Er:CaF₂ and 0.6at% Er:SrF₂.

Experimental oscillator strengths P_{exp} of the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ absorption transition were evaluated using relation [21]:

$$P_{exp} = \frac{mc}{\pi e^2 N} \int \alpha(\nu) d\nu$$
 (1)

In this expression, *m* is the electron mass, *e* is the electron charge, *N* is the Er³⁺ concentration, ν is the frequency and $\alpha(\nu)$ is the absorption coefficient expressed in cm⁻¹.

The integrals $f\alpha(\nu)d\nu$ correspond to the absorption bands and the resulting P_{exp} values are 2.27×10^{-6} and 1.85×10^{-6} for Er^{3+} : CaF₂ and Er^{3+} : SrF₂, respectively. The experimental oscillator strength $P_{exp} = 2.2 \times 10^{-6}$ of the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ absorption transition of Er^{3+} in CaF₂ reported by Kumar et al. [12] is consistent with our finding. It is worth noticing that the Er^{3+} concentration in a sample investigated in [12] is likely to be markedly smaller. The authors inconsistently state that Er concentration in the studied sample is 0.01 wt% and 0.01 at% in abstract of their article [12]. Peak absorption coefficient of 0.17 cm⁻¹ then reported [12] is smaller by a factor of 5, roughly than that measured for CaF₂ doped with 0.5at% Er³⁺ mentioned above.

When incorporating trivalent rare earth ion into CaF_2 or SrF_2 lattice the incorporated ion substitutes divalent Ca^{2+} or Sr^{2+} cation and the disparity of charge should be compensated. Different ways of charge compensation are possible, for instance co-doping with H⁺ ions [22], D⁺ ions [23], Na⁺ ions [24] or by incorporated F⁻ ions. Varieties of optical centers created by different ways are markedly different, however. In our samples the charge compensation is made by F⁻ ions located in the interstitial sites. It is commonly agreed that for a low doping level the luminescent

centers consist of a single Er³⁺ ion located in three possible sites: the tetragonal sites where the F^- is in the nearest neighbor interstitial site, the trigonal sites where the F⁻ is in the second nearest neighbor interstitial site and the cubic sites when F^- is far from the Er^{3+} ion. When the Er^{3+} concentration increases the dimer, trimer and more complex clusters showing completely dissimilar natures are formed. The onset of cluster creation is not a stepwise phenomenon. Consequently, the limit of a low doping level mentioned above is not obvious. Tallant and Wright [25] investigated CaF₂ crystal samples containing 0.01 mol% and 0.2 mol% of Er^{3+} employing a high resolution site selective spectroscopy. They concluded that the onset of clustering occurs already at 0.05 mol% concentration and it may be predominant at 0.3 mol% concentration. Brown et al. [26] investigated SrF₂ crystals doped with Er³⁺ ions with concentration ranged from 0 to 1% using electron spin resonance technique. The authors observed variation of tetragonal and trigonal sites and concluded that this can be explained by a calculation of relative energies of interstitial fluorine ions.

Figure 3 compares the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ absorption spectra recorded for $\text{Er}^{3+}:\text{CaF}_{2}$ and $\text{Er}^{3+}:\text{SrF}_{2}$ samples at 5 K. The spectrum for $\text{Er}^{3+}:\text{SrF}_{2}$ is inverted for the sake of clarity. We assign a line at 1536 nm in the $\text{Er}^{3+}:\text{CaF}_{2}$ spectrum to transition between the lowest crystal field component of the ground multiplet and the lowest crystal field component at energy 6512 cm⁻¹ of the ${}^{4}I_{13/2}$ multiplet (the 0–0 line). Similarly, we assign a line at 1540 nm (6496 cm⁻¹) as 0–0 line for

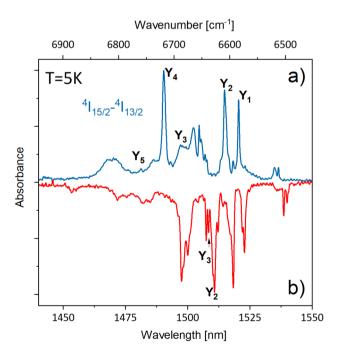


Fig. 3 The ${}^{4}I_{15/2}$ - ${}^{4}I_{13/2}$ absorption spectra recorded for **a** Er:CaF₂ and **b** Er:SrF₂ samples at 5 K. Spectrum for Er:SrF₂ is inverted for the sake of clarity. See text for explaining meanings of Y_i symbols

 Er^{3+} :SrF₂ sample. The spectra extend to about 1450 nm and consist of numerous components with the most prominent at 1490, 1514 and 1520 nm for Er³⁺ in CaF₂ and at 1497, 1510, 1518 and 1523 nm for Er³⁺:SrF₂. To understand spectral distribution of the observed bands we refer to results of extensive investigation performed in the past employing methods of EPR, site selective spectroscopy, optical Zeeman spectroscopy and infrared spectroscopy. Rector et al. [27] reported a study of EPR and optical Zeeman spectra of CaF₂ crystal containing 0.1 mol% Er³⁺ ions. The EPR spectra disclosed the existence of cubic, tetragonal and trigonal sites in the approximate ratios 15:20:1 whereas the optical spectrum consisted predominantly of lines due to tetragonal sites. The authors determined energies of 6 tetragonal (C_{4y}) CF levels of the ${}^{4}I_{13/2}$ multiplet. Five of them: 6572.9, 6602, 6684.7, 6716.8, 6747.2 cm^{-1} coincide with lines indicated by $Y_1 - Y_5$ in Fig. 3. Wells et al. [28] reported on polarized selective excitation studies of the C_{3v} symmetry centers in BaF_2 and SrF_2 doped with Er^{3+} . The authors determined energies of 6 trigonal (C_{3v}) CF levels of the ${}^{4}I_{13/2}$ multiplet for Er³⁺ in SrF₂. Two of them: 6622 and 6634 cm⁻¹ coincide with lines indicated by Y₂ and Y₃ in Fig. 3. Spectral lines due to cubic sites of rare earth ions in CaF₂ and SrF₂ have been also observed, for example, weakly luminescent transitions of Sm³⁺ in CaF₂ and SrF₂ have been assigned to centers of cubic symmetry [29]. More recently [24] luminescence of Nd³⁺ optical centers close to cubic symmetry in CaF₂ was observed, albeit their intensity was weak. The ${}^{4}I_{15/2} \leftrightarrow {}^{4}I_{13/2}$ magnetic dipole transitions are allowed therefore absorption and emission intensities of Er³⁺ in cubic sites may be higher. B. Jeżowska-Trzebiatowska et al. [30] investigated low temperature magnetic susceptibility, infrared and Raman spectra of Cs₂ErCl₆ single crystal in which Er^{3+} ions are located solely in sites of O_h symmetry. The authors found that the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ absorption spectrum at 5 K consists of predominant lines of magnetic dipole transitions ending on 5 CF levels of the ${}^{4}I_{13/2}$ state and markedly weaker vibronic lines induced by odd normal vibrations of the ErCl₆³⁻ moiety. The oscillator strength $P_{exp} = 0.33 \times 10^{-6}$ has been determined subsequently [31] for the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ transition. These findings indicate that the contribution of magnetic dipole transition is small and our values of oscillator strength for Er³⁺:CaF₂ and Er³⁺:SrF₂ are due mainly to electric dipole transitions in tetragonal and trigonal centers. Based on the low temperature ${}^4\mathrm{I}_{13/2} \,{\rightarrow}\, {}^4\mathrm{I}_{15/2}$ and

Based on the low temperature ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ and ${}^{4}S_{3/2} \rightarrow {}^{4}I_{15/2}$ emission spectra, it was found that overall ${}^{4}I_{15/2}$ ground state splitting is about 500 cm⁻¹ and 450 cm⁻¹ for Er³⁺:CaF₂ and Er³⁺:SrF₂, respectively. However, the several trigonal CF levels have been located above 496 cm⁻¹ in Er³⁺:SrF₂ [28]. It is worth noticing that details of the ground state splitting provided by luminescence and EPR spectroscopy are supplemented by far infrared spectroscopy. In fact, Aubry et al. [32] investigated absorption spectra in the region 17–170 cm⁻¹ and Zeeman effect at 1.4 K for SrF₂ crystal containing rare earth ions with concentration of 0.2 mol%. They attributed lines observed at 32.8 and 43.5 cm⁻¹ to electronic transition of Er^{3+} ions in tetragonal site (C_{4v}) and a line at 81.3 cm⁻¹ to electronic transition of Er^{3+} ions in cubic site (O_b).

Figure 4 compares absorption spectra (upper) and emission spectra (medium) at several different temperatures between 80 and 300 K for $Er^{3+}:CaF_2$ crystal. Graphs in the bottom are plots of the gain coefficient G (λ) evaluated according to the relation [33]:

$$\mathbf{G}(\boldsymbol{\lambda}) = \mathbf{N} \left[\mathbf{P} \boldsymbol{\sigma}_{\mathbf{e}}(\boldsymbol{\lambda}) - (1 - \mathbf{P}) \boldsymbol{\sigma}_{\mathbf{a}}(\boldsymbol{\lambda}) \right]$$
(2)

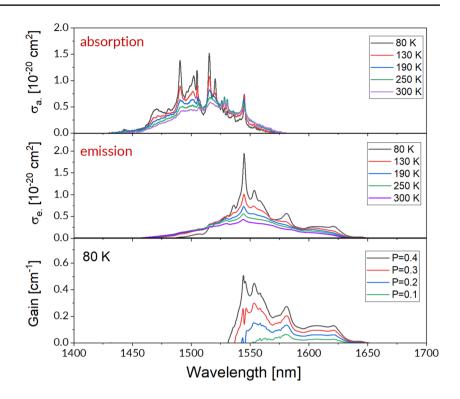
where, N is Er^{3+} ions concentration, P denotes a population inversion parameter defined as the ratio of erbium ions density in the excited state to the overall erbium ion density in the crystal, $\sigma_{e.}(\lambda)$ is the stimulated-emission cross-section and $\sigma_{a.}(\lambda)$ is the absorption cross-section.

To compare absorption ability of samples differing in chemical composition and/or density of absorbing ions the absorption spectrum is expressed in cross-section units. Five temperatures were chosen.

At 300 K the higher energy crystal field components of the two multiples involved cannot be assumed empty and the spectra measured are envelopes of numerous spectral lines related to transitions between individual crystal field levels. When the temperature diminishes the populations of higher energy crystal field levels of initial multiplets become smaller. As a consequence the spectra at 80 K show more pronounced structure. Nevertheless, at 80 K the kT ~ 56 cm⁻¹ and the Bolztmann statistics indicates that the population of the higher energy components of the ground multiplet ${}^{4}I_{15/2}$ is close to 30% of total multiplet population and thereby absorption spectra recorded at 80 K remain still complex. Well defined absorption maxima at 1490.5, 1504.5, 1515 and 1520 nm are convenient for optical pumping. Their spectral widths are large enough to match typical bandwidth of laser diode emission of 2 nm. It is worth noticing that these four maxima are preponderant also in 5 K absorption spectra (shown in Fig. 3) indicating that they are related to transitions from the lowest energy crystal field levels of the ground state. Examination of the absorption bands in Fig. 4 reveals clearly that the overall band areas and the band structures diminish when the temperature increases from 80 to 300 K.

The middle panel in Fig. 4 shows the ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ emission spectra calibrated in units of stimulated-emission cross section σ_{e} using the Füchtbauer-Ladenburg (FL) relation [34]:

Fig. 4 Absorption cross section spectra (upper), stimulatedemission cross section spectra (medium) at several different temperatures between 80 and 300 K and gain G spectra at 80 K (bottom) for 0.5at% Er:CaF₂ crystal



$$\sigma_{e.}(\lambda) = \frac{\beta}{8\pi n^2 c\tau} \frac{\lambda^5 \mathbf{I}(\lambda)}{\int \lambda \mathbf{I}(\lambda) d\lambda}$$
(3)

symbols *c*, *m* and *e* denote speed of light, electron mass and electron charge respectively.

Emission spectrum at 80 K shows well defined local maxima at 1545, 1554, 1581 and 1621 nm. When the temperature increases the overall emission band intensity diminishes and its structure is less complex.

In Fig. 5 the values of absorption cross section and emission cross section at the wavelengths of local maxima mentioned above for Er³⁺:CaF₂ are plotted versus temperature in the region 80 K - 300 K. It can be seen that the local maximum at 1515 nm shows the highest absorption cross section for all wavelengths in this region. The change of temperature from 80 to 300 K brings about a decrease of its peak absorption cross section from 1.52×10^{-20} cm² to 0.59×10^{-20} cm². For the same change of the temperature the peak absorption cross section at remaining wavelengths decreases by a factor of 2 roughly. The peak stimulated-emission cross section is the highest at 1545 nm. It attains 1.95×10^{-20} cm² at 80 K and 0.43×10^{-20} cm² at 300 K. Values of the peak stimulated-emission cross section at remaining wavelengths mentioned above are lower and their dependence on the temperature is rather moderate.

Figure 6 compares absorption spectra (upper) and emission spectra (medium) at several different temperatures between 80 and 300 K for Er^{3+} :SrF₂ crystal. Five temperatures were chosen. Well defined absorption maxima at 1498, 1508.5, 1510.5 and 1518 nm are convenient for

where
$$I(\lambda)/\hat{\lambda}I(\lambda)d\lambda$$
 is a normalized lineshape function of
the experimental emission spectrum $I(\lambda)$, luminescence
branching ratio $\beta = 1$ for the ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ Er³⁺ transition,
 τ is the ${}^{4}I_{13/2}$ radiative lifetime, *n* is the refractive index
and *c* is the velocity of light. To obtain spectra $\sigma_{e}(\lambda)$ from
Eq. (3) the radiative lifetime values τ should be known. The
 ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ transition obeys the selection rules $\Delta L = 0$,
 $\Delta S = 0$, $\Delta J = 0,1$ ($0 \neq 0$). Hence, magnetic dipole transi-
tions are allowed and the relaxation rate of the ${}^{4}I_{13/2}$ excited
state of Er³⁺ is a sum of the electric dipole transition rate
 $A(ED)$ and of the magnetic dipole transition rate $A(MD)$.
The inverse of the sum $A(ED) + A(MD)$ is the ${}^{4}I_{13/2}$ radiative

The inverse of the sum A(ED) + A(MD) is the ${}^{4}I_{13/2}$ radiative lifetime τ . Values of the oscillator strength P(MD) and corresponding rate A(MD) for magnetic dipole transition were calculated using relations given elsewhere [21]. The calculated P(MD) value was then subtracted from experimental oscillator strengths P_{exp} and eventually, electric dipole oscillator strengths P(ED) were obtained. Next, values of the A(ED) were determined inserting P(ED) to the relation [21]:

$$\mathbf{A}(\mathbf{ED}) = \frac{8\pi^2 \mathbf{e}^2 \mathbf{n}^2}{\mathbf{mc}\lambda^2} \times \frac{2\mathbf{J}' + 1}{2\mathbf{J} + 1} \times \mathbf{P}(\mathbf{ED})$$
(4)

where *n* is the refractive index, the values of *J*' and *J* are 13/2 and 15/2 respectively, λ denotes emission wavelength,

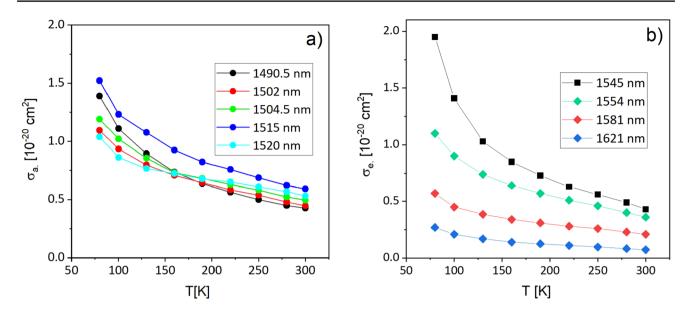
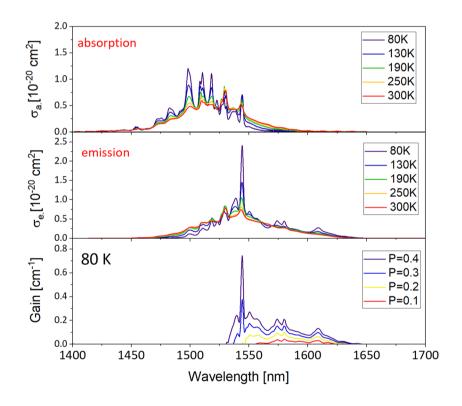


Fig. 5 Absorption cross section (a) and stimulated-emission cross section (b) at wavelengths of several local maxima for $Er:CaF_2$ plotted versus temperature in the region 80 K – 300 K

Fig. 6 Absorption cross section spectra (upper), stimulatedemission cross section spectra (medium) at several different temperatures between 80 and 300 K and gain G spectra at 80 K (bottom) for 0.6at% Er:SrF₂ crystal



optical pumping. Their spectral widths are large enough to match typical bandwidth of laser diode emission of 2 nm. Four maxima given above are preponderant also in 5 K absorption spectra (shown in Fig. 3) indicating that they are related to transitions from the lowest energy crystal field levels of the ground state. Examination of absorption bands in Fig. 6 reveals clearly that the overall band

areas diminish and the band structures vanish when the temperature increases from 80 to 300 K.

The emission spectrum at 80 K shows well defined local maxima at 1544, 1574, 1580 and 1609 nm. When the temperature increases the overall emission band intensity diminishes an its structure becomes weaker.

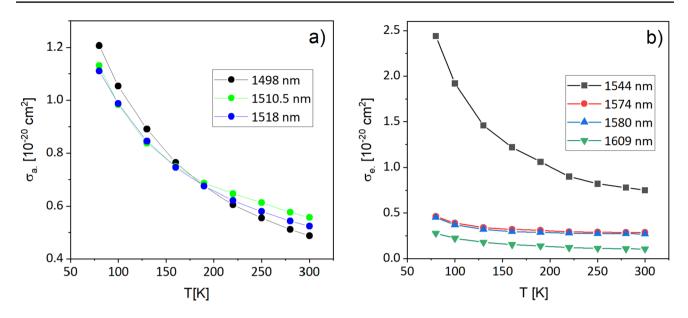


Fig. 7 Absorption cross section (a) and stimulated-emission cross section (b) at wavelengths of several local maxima for Er:SrF_2 plotted versus temperature in the region 80 K – 300 K

In Fig. 7 the values of absorption cross section and stimulated-emission cross section at wavelengths of local maxima mentioned above for Er^{3+} :SrF₂ are plotted versus temperature in the region 80 K – 300 K. It can be seen that the local maximum at 1498 nm shows the highest absorption cross section of about 1.22×10^{-20} cm² at 80 K but its decrease is steep and at 300 K it is the smallest amounting to 0.49×10^{-20} cm². The values of absorption cross section for local maxima at remaining wavelengths are smaller and their dependence on the temperature is rather moderate. The peak emission cross section is the highest at 1544 nm. It attains 2.44×10^{-20} cm² at 80 K and 0.75×10^{-20} cm² at 300 K. The values of the peak stimulated-emission cross section at remaining wavelengths mentioned above are markedly lower and their dependence on the temperature is rather moderate.

Our stimulated-emission cross section data depend crucially on radiative lifetime values inserted to Eq. (3). Labbe et al. [4] have determined $\tau = 7.7$ ms for the ${}^{4}I_{13/2}$ level of Er³⁺ in CaF₂. This value was obtained from the Judd–Ofelt analysis of absorption spectra averaged over several Er³⁺ concentrations between 0.49 at% and 10.34 at%. The J-O parameters then obtained are: $\Omega_2 = 1.22$, $\Omega_4 = 0.98$, $\Omega_6 = 1.72$ (in units of 10^{-20} cm²). Kumar et al. [12] performed the Judd-Ofelt analysis of absorption spectra recorded for Er:CaF₂. They obtained the J-O parameters: $\Omega_2 = 6.6$, $\Omega_4 = 2.3$, $\Omega_6 = 2.0$ (in units of 10^{-20} cm²). These values are markedly higher than those reported by Labbe et al. but curiously they gave longer $\tau = 8.4$ ms. In our approach $\tau = 7.1$ ms at 300 K for Er:CaF₂ and τ = 7.6 at 300 K for Er:SrF₂ was determined employing Eq. (4), (fundamental formula of absorption spectroscopy) [35]. It can be seen that three τ values for the ${}^{4}I_{13/2}$ level of Er^{3+} in CaF_{2} mentioned above agree quite well. However in view of significant differences in the J-O parameters involved this agreement may be accidental. In our opinion the reliability of this parameter waits for the verification.

Actual emission cross-section values for the ${}^{4}I_{13/2} \rightarrow {}^{4}I_{15/2}$ transition will be smaller due to the adverse effect of selfabsorption. Graphs included in the bottom of Figs. 4 and 6 show a plot of a gain coefficient $G(\lambda)$ at 80 K for several small values of population inversion parameter P versus wavelength according to Eq. (2). It is worth noticing that S.A. Pollack in his pioneer work [1] observed a free running laser operation at 1617 nm at 77 K. Our emission and $G(\lambda)$ spectra at 80 K shown in Fig. 4 are consistent with this report. It follows from Eq. (2) that in regions where σ_a may be neglected, i.e. at wavelengths longer than 1590 nm for Er:CaF₂ and 1600 nm for Er:SrF₂ the G(λ) values at 80 K and 300 K would be essentially the same. In fact, it can be seen in Figs. 4&6 that σ_e is affected weakly by the temperature and at 300 K it equals to $\sim 0.07 \times 10^{-20}$ cm² at 1621 nm for CaF₂:Er and to ~ 0.1×10^{-20} cm² at 1609 nm for Er:SrF₂. Even for the parameter P as small as 0.1 the corresponding $G(\lambda)$ values are higher nearly by one order of magnitude than scatter losses encountered in laser crystals, typically ~ 0.001–0.002 cm⁻¹ [36]. The plots of $G(\lambda)$ imply also that for higher P parameters the Er:CaF₂ and Er:SrF₂ lasers with a properly chosen dispersive element inserted in a laser cavity would be able to emit radiation tuned between about 1575 nm and 1620 nm. Significant advantage of resonantly pumped erbium lasers emitting near 1.6 µm resides in that the difference between absorbed and emitted photon energy, denoted as quantum defect (QD) is very small. In fact, in Er:CaF₂ laser emitting at 1621 nm, pumped at 1504.5 nm the QD=480 cm⁻¹, i.e. ~7% of absorbed pump energy that is converted to heat in a laser crystal. Similarly, in Er:SrF₂ laser emitting at 1609 nm, pumped at 1498 nm the QD=461 cm⁻¹, i.e. ~6.9% of absorbed pump energy that is converted to heat in a laser crystal. When pumping into absorption bands located at wavelengths closer to the wavelength of the 0–0 line the QD value would be markedly smaller.

4 Conclusions

Room temperature absorption spectra related to the ${}^{4}I_{15/2} \rightarrow {}^{4}I_{13/2}$ transition of Er^{3+} ions in single crystal samples of CaF_2 containing 0.05, 0.1, 0.3, 0.5 at% Er^{3+} were found to be similar with respect to the overall band width and the distribution of local maxima contained therein. The same conclusion concerns single crystal samples of SrF₂ containing 0.05, 0.1, 0.2, 0.6 at%Er³⁺. Spectra recorded for samples cooled down to 5 K were analyzed referring to published data of EPR [27], high resolution selective laser spectroscopy and far infrared absorption investigation indicating that preponderant optical centers consist of single Er³⁺ ions in tetragonal, trigonal and cubic sites. Analysis of absorption and luminescence spectra recorded at several temperatures from 80 to 300 K provided an in-depth knowledge on effects of temperature on factors that govern the efficiency of resonant optical pumping and lasing ability of Er^{3+} ions imbedded in CaF_2 and SrF_2 hosts. For instance, a local absorption maxima at 1515 nm and 1498 nm show the highest absorption cross section at all wavelengths in this region for Er:CaF₂ and Er:SrF₂, respectively. The peak stimulated-emission cross section is the highest at 1545 nm for the two systems. It attains 1.95×10^{-20} cm² at 80 K and 0.43×10^{-20} cm² at 300 K for Er:CaF₂ and 2.44×10^{-20} cm² at 80 K and 0.75×10^{-20} cm² at 300 K for Er:SrF₂. Quantum defect (QD) value for the two systems is below 10%.

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Declarations

Conflict of interest The authors declare no competing interests.

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